

THERMAL PERFORMANCE				
PARAMETER	SYMBOL	ТҮР	UNIT	
Junction-to-case resistance	R _{eJC}	2	°C/W	

ELECTRICAL SPECIFICATIONS ($T_A = 25^{\circ}C$ unless otherwise noted)						
PARAMETER		CONDITIONS	SYMBOL	ТҮР	MAX	UNIT
Forward voltage ⁽¹⁾	HERA801G HERA802G HERA803G HERA804G	I _F = 8A, T _J = 25°C	V _F	-	1.0	V
	HERA805G			-	1.3	V
	HERA806G HERA807G HERA808G			-	1.7	V
Reverse current @ rated V _R ⁽²⁾		T _J = 25°C	I _R	-	10	μA
		T _J = 125°C		-	400	μA
Junction capacitance	HERA801G HERA802G HERA803G HERA804G HERA805G	1MHz, V _R = 4.0V	CJ	65	-	pF
	HERA806G HERA807G HERA808G			55	-	pF
Reverse recovery time	HERA801G HERA802G HERA803G HERA804G HERA805G	IF = 0.5A, IR = 1.0A Irr = 0.25A	t _{rr}	-	50	ns
	HERA806G HERA807G HERA808G			-	80	ns

Notes:

1. Pulse test with PW = 0.3ms

2. Pulse test with PW = 30ms

ORDERING INFORMATION				
ORDERING CODE ⁽¹⁾⁽²⁾	PACKAGE	PACKING		
HERA8xG	TO-220AC	50 / Tube		
HERA8xGH	TO-220AC	50 / Tube		

Notes:

1. "x" defines voltage from 50V(HERA801G) to 1000V(HERA808G)

2. "H" means AEC-Q101 qualified



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CHARACTERISTICS CURVES

 $(T_A = 25^{\circ}C \text{ unless otherwise noted})$

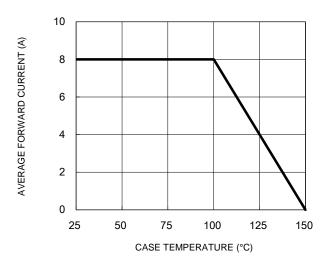


Fig.1 Forward Current Derating Curve

Fig.3 Typical Reverse Characteristics

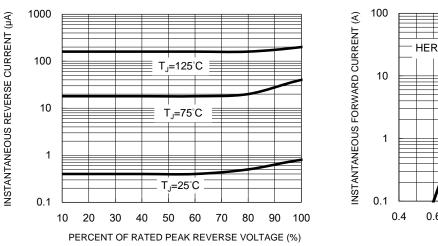
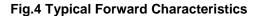


Fig.2 Typical Junction Capacitance



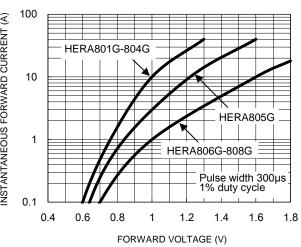
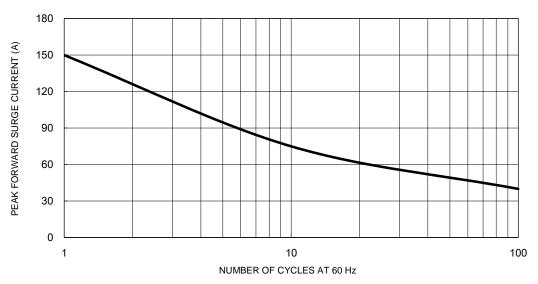


Fig.5 Maximum Non-Repetitive Forward Surge Current

CAPACITANCE (pF)





CHARACTERISTICS CURVES

 $(T_A = 25^{\circ}C \text{ unless otherwise noted})$

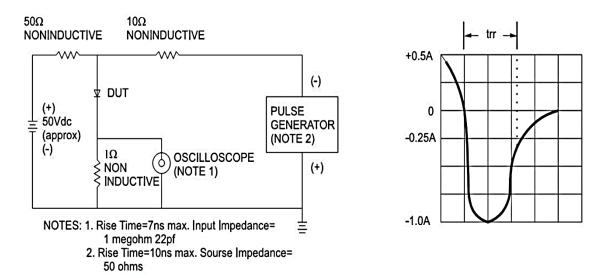


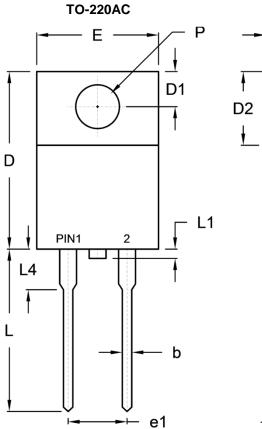
Fig.6 Reverse Recovery Time Characteristic and Test Circuit Diagram



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PACKAGE OUTLINE DIMENSIONS



2			c2
	 A2	<u>_</u>	

DIM.	Unit	Unit (mm)		(inch)
DIN.	Min.	Max.	Min.	Max.
А	4.42	4.76	0.174	0.187
A2	2.20	2.80	0.087	0.110
b	0.68	0.94	0.027	0.037
с	0.35	0.64	0.014	0.025
c2	1.14	1.40	0.045	0.055
D	14.60	16.00	0.575	0.630
D1	2.62	3.44	0.103	0.135
D2	5.84	6.86	0.230	0.270
E	-	10.50	-	0.413
e1	4.95	5.20	0.195	0.205
L	13.19	14.79	0.519	0.582
L1	0.00	1.60	0.000	0.063
L4	2.80	4.20	0.110	0.165
Р	3.54	4.00	0.139	0.157

MARKING DIAGRAM



P/N	= Marking Code
G	= Green Compound
YWW	= Date Code
F	= Factory Code



HERA801G – HERA808G

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